

Receipt date: 06/06/2011

OK TO ENTER: /E.B./ IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

06/08/2011

Application No.:	10/553,573
Applicants:	Christian DUSSARRAT et al.
Filed Internationally:	April 8, 2004
US National:	October 17, 2005
Title:	METHODS FOR PRODUCING SILICON NITRIDE FILMS BY VAPOR-PHASE GROWTH
TC/A.U.:	1715
Examiner:	Elizabeth A. Burkhart
Docket No.:	Serie 6070
Customer No.:	40582

AMENDMENT AFTER FINAL

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

In response to the Final Office Action mailed April 4, 2011, having a shortened statutory period for response set to expire on July 4, 2011, Applicants respectfully request reconsideration of the present application in view of the following amendments and/or remarks:

Amendments to the Claims begin on page 2 of this paper.

Remarks begin on page 4 of this paper.